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November 2013



# FGH30N60LSD 600 V, 30 A PT IGBT

## Features

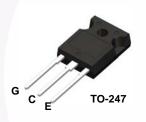
- Low Saturation Voltage:  $V_{CE(sat)} = 1.1 \text{ V} @ I_C = 30 \text{ A}$
- High Input Impedance
- Low Conduction Loss

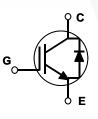
## Applications

Solar Inverter, UPS

# **General Description**

Using Fairchild's advanced PT technology, the FGA30N60LSD IGBT offers superior conduction performances, which offer the optimum performance for medium switching application such as solar inverter, UPS applications where low conduction losses are the most important factor.





# **Absolute Maximum Ratings**

Symbol	Description	Ratings	Unit	
V <sub>CES</sub>	Collector-Emitter Voltage	600	V	
V <sub>GES</sub>	Gate-Emitter Voltage		± 20	V
	Collector Current @ $T_C = 25^{\circ}C$		Current @ $T_{C} = 25^{\circ}C$ 60	
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 100°C	30	А
I <sub>CM (1)</sub>	Pulsed Collector Current	90	A	
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		150	A
Maximum Power Dissipation		@ T <sub>C</sub> = 25°C	480	W
P <sub>D</sub> Maximu	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	192	W
TJ	Operating Junction Temperature	-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C	

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

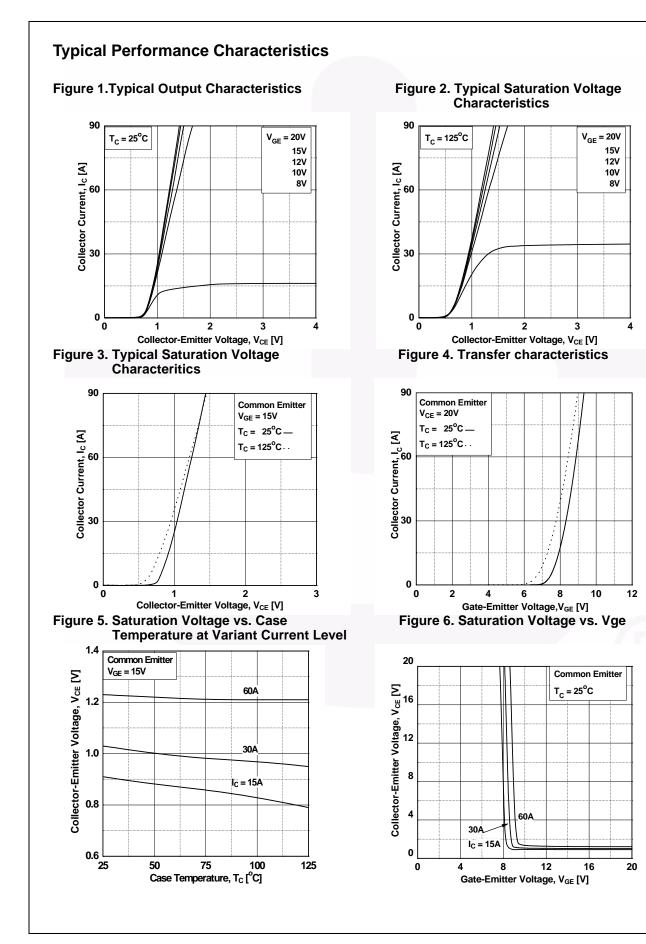
## **Thermal Characteristics**

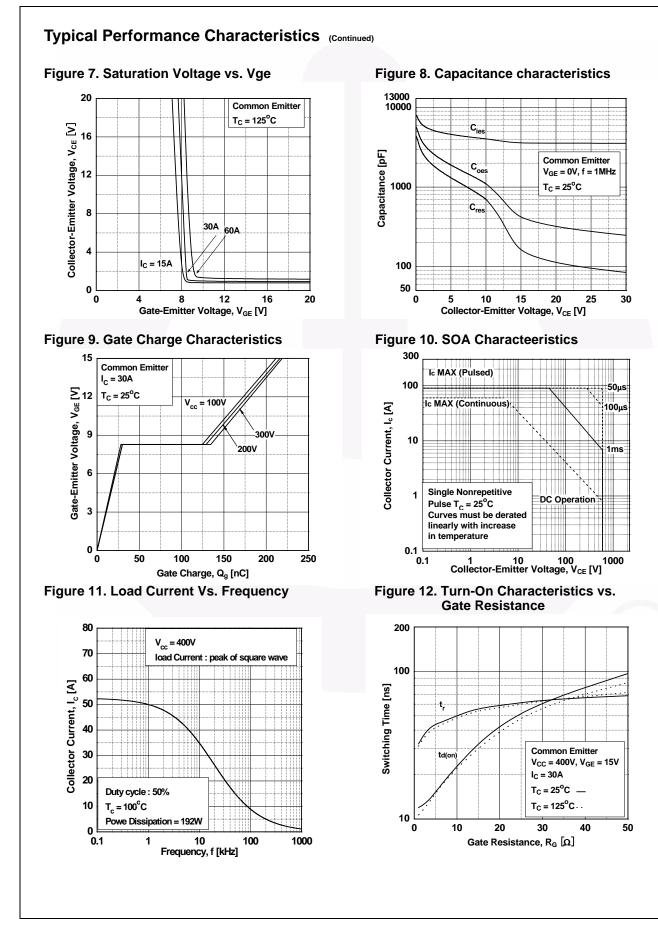
Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction-to-Case		0.26	°C/W
$R_{\theta JC}$ (Diode)	Diode) Thermal Resistance, Junction-to-Case		0.92	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

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Part NumberTop MarkPackageFGH30N60LSDTUFGH30N60LSDTO-247		Package	kage Packing Method Re		Tape Width		Quantity	
		TO-247	Tube	N/A	N/A		30	
Electric	al Cha	aracteristics	of the IG	<b>BT</b> $T_{C} = 25^{\circ}C$ unless otherw	vise noted			
Symbol		Parameter		Test Condition	ns Min.	Тур.	Max.	Unit
Off Charac	teristics							
BV <sub>CES</sub>	Collector-Emitter Breakdown Voltage		V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 uA	600			V	
ΔB <sub>VCES</sub> / ΔT <sub>.1</sub>	Temperature Coefficient of Breakdown Voltage			$V_{GE} = 0 V, I_C = 250 uA$		0.6		V/°C
I <sub>CES</sub>	-	r Cut-Off Current		V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V			250	uA
I <sub>GES</sub>	G-E Lea	akage Current		$V_{GE} = V_{GES}, V_{CE} = 0 V$			±250	nA
On Charac	teristics							
V <sub>GE(th)</sub>		eshold Voltage		I <sub>C</sub> = 250 uA, V <sub>CE</sub> = V <sub>GE</sub>	4.0	5.5	7.0	V
GE(III)				$I_{\rm C} = 30$ A, $V_{\rm GE} = 15$ V		1.1	1.4	V
V <sub>CE(sat)</sub> Collector to B Saturation V				$I_{C} = 30 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$		1.0		V
				I <sub>C</sub> = 60 A, V <sub>GE</sub> = 15 V		1.3		V
Dynamic C	haracter	istics	Ľ		i			
C <sub>ies</sub>	1	apacitance				3550		pF
C <sub>oes</sub>	Output Capacitance			$V_{CE} = 30 V, V_{GE} = 0 V,$		245		pF
C <sub>res</sub>	Reverse Transfer Capacitance			f = 1 MHz		90		pF
Switching	Characte	eristics			L L			
t <sub>d(on)</sub>	1	Delay Time				18		ns
t <sub>r</sub>		Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss				46		ns
t <sub>d(off)</sub>	Turn-Of			V <sub>CC</sub> = 400 V, I <sub>C</sub> = 30 A,		250	)	ns
<u>-()</u> t <sub>f</sub>	Fall Tim			$R_{G} = 6.8 \Omega$ , $V_{GE} = 15 V$ ,		1.3	2.0	us
E <sub>on</sub>	Turn-Or			Inductive Load, $T_C = 25^{\circ}C$		1.1		mJ
E <sub>off</sub>	Turn-Of	f Switching Loss				21		mJ
t <sub>d(on)</sub>	Turn-Or	Turn-On Delay Time Rise Time Turn-Off Delay Time				17		ns
t <sub>r</sub>	Rise Tin					45		ns
t <sub>d(off)</sub>	Turn-Of			V <sub>CC</sub> = 400 V, I <sub>C</sub> = 30 A,		270		ns
t <sub>f</sub>	Fall Time			$R_G = 6.8 \Omega$ , $V_{GE} = 15 V$ , Inductive Load, $T_C = 125^{\circ}C$		2.6		us
E <sub>on</sub>	Turn-Or	urn-On Switching Loss				1.1		mJ
E <sub>off</sub>	Turn-Of	f Switching Loss				36		mJ
Q <sub>g</sub>	Total Ga	ate Charge				225		nC
Q <sub>ge</sub>	Gate-Er	nitter Charge		$V_{CE} = 600 \text{ V}, I_{C} = 30 \text{ A},$ $V_{GE} = 15 \text{ V}$		30		nC
Q <sub>gc</sub>	Gate-Co	ollector Charge				105		nC
L <sub>e</sub>	Internal	Emitter Inductance		Measured 5mm from PKC	G	7		nH

Parameter	Conditions			Тур.	Max	Unit
V <sub>FM</sub>	I <sub>F</sub> = 15 A	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	-	1.8	2.2	V
* FM	I <sub>F</sub> = 15 A	T <sub>C</sub> = 125 °C	-	1.6	-	V
I <sub>RM</sub>	V <sub>R</sub> = 600 V	T <sub>C</sub> = 25 °C	-	-	100	μA
t <sub>rr</sub>	I <sub>F</sub> =1 A, di <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V	T <sub>C</sub> = 25 °C	-	-	35	ns
	$I_F = 15 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 390 \text{ V}$	T <sub>C</sub> = 25 °C	-	-	40	ns
t <sub>a</sub>		T <sub>C</sub> = 25 °C	-	18	-	ns
t <sub>b</sub>	I <sub>F</sub> =15 A, di <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 390 V	T <sub>C</sub> = 25 °C	-	13	-	ns
Q <sub>rr</sub>		T <sub>C</sub> = 25 °C	-	27.5	-	nC





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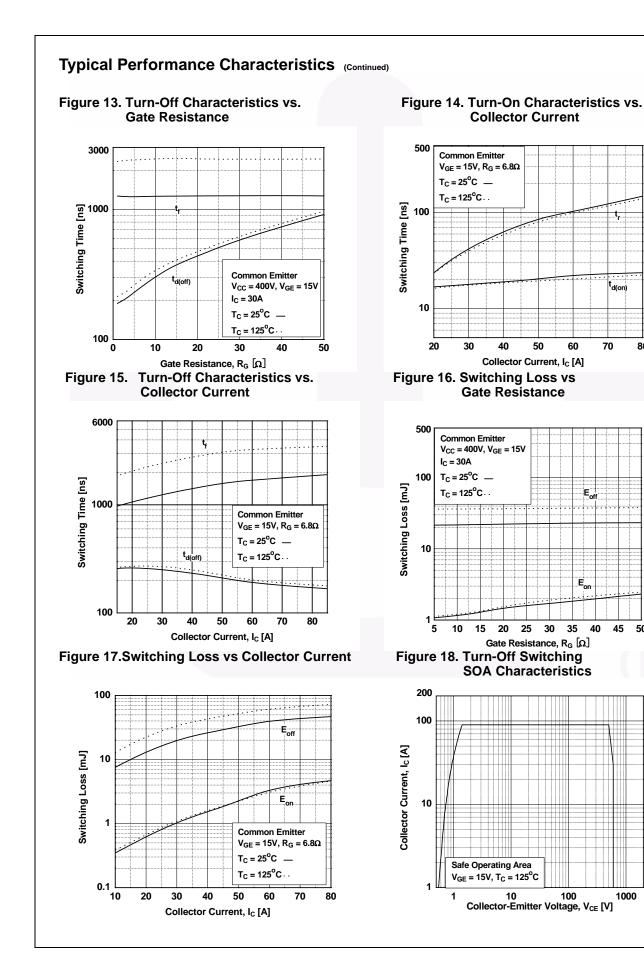
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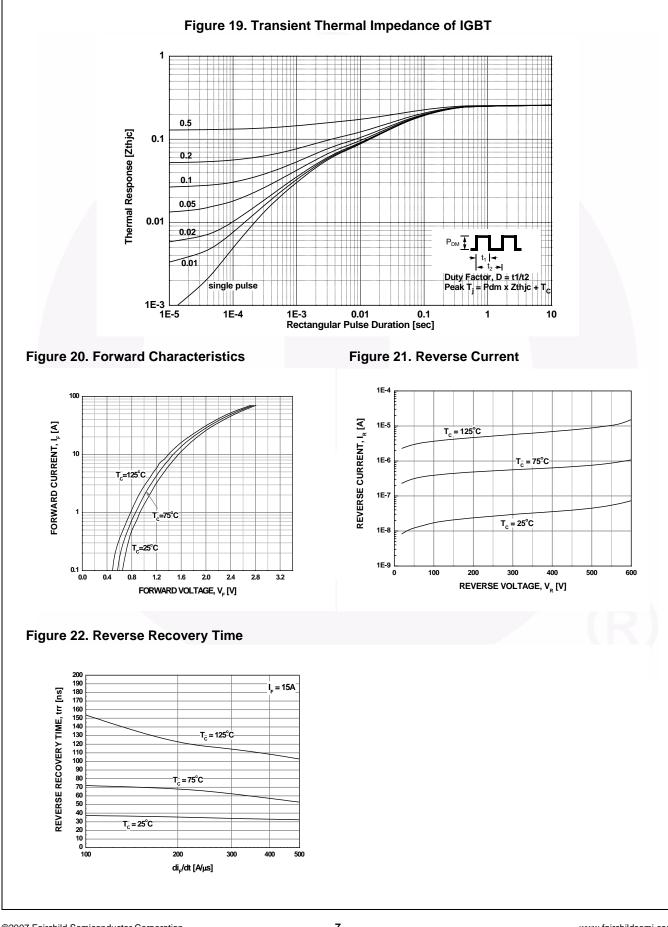
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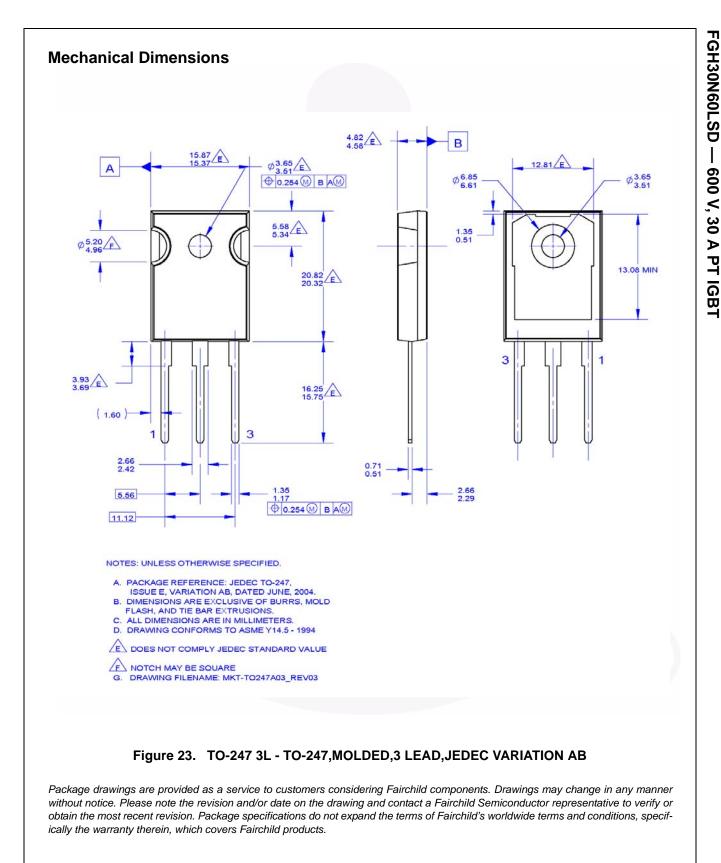


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GH30N60LSD —

600 V, 30 A PT IGBT

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